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	Application No.	Applicant(s)	
Made CAR LUC	09/945,554	FORBES, LEONARD	
Notice of Allowability	Examiner	Art Unit	
	Thomas L Dickey	2826	
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED or other appropriate comn (IGHTS. This application is	in this application. If not include nunication will be mailed in due c	d ourse. THIS
1. This communication is responsive to <u>amendment filed 18</u>	March 2003		
2. X The allowed claim(s) is/are 1-12,19-27,29-44 and 46-49.	Water Love.		
3. The drawings filed on 30 August 2001 are accepted by the	e Examiner.		
4. Acknowledgment is made of a claim for foreign priority un a) All b) Some* c) None of the:		or (f).	
1. Certified copies of the priority documents have	e been received.		
2. Certified copies of the priority documents have	e been received in Applicat	ion No	
3. Copies of the certified copies of the priority do	cuments have been receiv	ed in this national stage applicati	on from the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
5. Acknowledgment is made of a claim for domestic priority u	- ', '	• • • • • • • • • • • • • • • • • • • •	
(a) The translation of the foreign language provisional a			
6. Acknowledgment is made of a claim for domestic priority u	nder 35 U.S.C. §§ 120 and	l/or 121.	
Applicant has THREE MONTHS FROM THE "MAILING DATE" o below. Failure to timely comply will result in ABANDONMENT of			
7. A SUBSTITUTE OATH OR DECLARATION must be subr			OTICE OF
 8. CORRECTED DRAWINGS must be submitted. (a) including changes required by the Notice of Draftsper 1) hereto or 2) to Paper No. (b) including changes required by the proposed drawing 	correction filed, wh	ich has been approved by the Ex	
(c) including changes required by the attached Examiner	's Amendment / Comment	or in the Office action of Paper N	0
Identifying indicia such as the application number (see 37 CFR 1 of each sheet. The drawings should be filed as a separate paper	.84(c)) should be written on r with a transmittal letter add	the drawings in the top margin (no lressed to the Official Draftspersor	ot the back) I.
9. DEPOSIT OF and/or INFORMATION about the depo attached Examiner's comment regarding REQUIREMENT FOR T	ISIT OF BIOLOGICAL MAT THE DEPOSIT OF BIOLOG	FERIAL must be submitted. No SICAL MATERIAL.	ote the
Attachment(s)			
 1 ☐ Notice of References Cited (PTO-892) 3 ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 5 ☐ Information Disclosure Statements (PTO-1449), Paper No. 9 7 ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	4∏ Intervie 9. 6 ⊠ Examir	of Informal Patent Application (Pew Summary (PTO-413), Paper Neer's Amendment/Comment ner's Statement of Reasons for A	lo
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		Min'n Loan	
		Primary coal	ini ief

Application/Control Number: 09/945,554

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EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Marvin Beekman on 21 April 2003.

The application has been amended as follows:

IN THE CLAIMS:

Cancel claims 13-18, 28, and 45.

In claim 46, line 1, change "claim 45" to -claim 43-

REASONS FOR ALLOWANCE

2. The following is an examiner's statement of reasons for allowance:

Claims 43,44 and 46-49 are allowed over the references of record because none of these references disclosed or can be combined to yield the claimed invention such as a method for operating an SRAM cell which includes a pair of cross coupled floating gate transistors, comprising: writing to at least one of the cross coupled floating gates of the SRAM cell using channel hot electron injection, wherein the cross coupled floating gate transistors each include: a first

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source/drain region and a second source/drain region separated by a channel region in a substrate; a floating gate opposing the channel region and separated therefrom by a gate oxide; and a control gate opposing the floating gate, wherein the control gate is separated from the floating gate by a low tunnel barrier intergate insulator; erasing charge from the floating gate by tunneling electrons off of the floating gate and onto the control gate; sensing a logic state of the SRAM cell in a start up mode; and writing to the floating gate by tunneling electrons from the control gate to the floating gate., as recited in claim 43.

Claims 1-12,19-27, and 29-42 are allowed over the references of record because none of these references disclosed or can be combined to yield the claimed invention such as memory cell comprising at least a pair of cross coupled inverters, wherein each inverter includes an NMOS transistor and a PMOS transistor, and wherein at least one of the NMOS transistors includes: a first source/drain region and a second source/drain region separated by a channel region in a substrate; a floating gate opposing the channel region and separated therefrom by a gate oxide; and a control gate opposing the floating gate, wherein the control gate is separated from the floating gate by a low tunnel barrier intergate insulator, as recited in claims 1,9,19,24,33, and 39.

Forbes et al. discloses a memory cell, or a method for making the same, with a pair of cross coupled inverters 206-308 and 210-312, wherein each inverter includes an NMOS transistor 308,312 and a PMOS transistor 206,210, and

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wherein at least one of the NMOS transistors 308,312 includes: a first source/drain region 118 and a second source/drain region 122 separated by a channel region 120a in a substrate 120; a floating gate 116 opposing the channel region 120a and separated therefrom by a gate oxide 126; and a control gate 114 opposing the floating gate 116, wherein the control gate 114 is separated from the floating gate 116 by a intergate insulator 124; and a conformal method of forming said memory cell, comprising: forming the said pair of cross coupled inverters 206-308 and 210-312, wherein forming each said inverter includes an NMOS transistor 308,312 and a PMOS transistor 206,210, and wherein the method includes forming at least one of the NMOS transistors 308,312 to include: the said first source/drain region 118 and the said second source/drain region 122 separate by the said channel region 120a in the said substrate 120; the said floating gate 116 opposing the said channel region 120a and separated therefrom by the said gate oxide 126; and the said control gate 114 opposing the said floating gate 116, wherein the said control gate 114 is separated from the said floating gate 116 by the said intergate insulator 124. Note figures 5B and 8A and column 5 lines 1-60 of Forbes et al. However, the only disclosed property of Forbes's integrate insulator 124 is that it be dielectric – it is not disclosed as having any other properties, nor is it disclosed as being made of any particular material. Nishimura discloses a four transistor SRAM cell with floating gate transistors comprising: a pair of cross coupled NMOS floating gate 30 transistors MT1 and

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MT2, wherein each of the pair of cross coupled NMOS transistors MT1 and MT2 includes: a first source/drain region 22 and a second source/drain region 24 separated by a channel region 26 in a substrate 20; a floating gate 30 opposing the channel region 26 and separated therefrom by a gate oxide 28; and a control gate 34 opposing the floating gate 30, wherein the control gate 34 is separated from the floating gate 30 by an intergate insulator 32. Note figures 3A, 3B, and 11 of Nishimura. However, the only disclosed property of Nishimura's intergate insulator 32 is that it be ferroelectric – it is not disclosed as having any other properties, nor is it disclosed as being made of any particular material. Although it might be possible to form a low tunnel barrier intergate insulator by following the teachings of Forbes or Nishimura, it is equally possible to not form a low tunnel barrier intergate insulator by following the teachings of Forbes or Nishimura.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thomas L Dickey whose telephone number is

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703-308-0980. The examiner can normally be reached on Monday through Thursday 8 AM to 6 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (703) 308-6601. The fax phone numbers for the organization where this application or proceeding is assigned are 703-308-7722 for regular communications and 703-872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3431.

04/2003



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NOTICE OF ALLOWANCE AND FEE(S) DUE

7590 05/02/2003 SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938 Minneapolis, MN 55402		DICKEY, THOMAS L		
			·	
at the			DATE MAILED: 05/02/2003	
APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/945,554	08/30/2001 تعتقیمی	Leonard Forbes	1303.028US1	1837

TITLE OF INVENTION: SRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATORS

APPLN. TYPE	SMALL ENTITY	ISSUE FEE	PUBLICATION FEE	TOTAL FEE(S) DUE	DATE DUE
nonprovisional	NO	\$1300	\$300	\$1600	08/04/2003

THE APPLICATION IDENTIFIED ABOVE HAS BEEN EXAMINED AND IS ALLOWED FOR ISSUANCE AS A PATENT. <u>PROSECUTION ON THE MERITS IS CLOSED.</u> THIS NOTICE OF ALLOWANCE IS NOT A GRANT OF PATENT RIGHTS. THIS APPLICATION IS SUBJECT TO WITHDRAWAL FROM ISSUE AT THE INITIATIVE OF THE OFFICE OR UPON PETITION BY THE APPLICANT. SEE 37 CFR 1.313 AND MPEP 1308.

THE ISSUE FEE AND PUBLICATION FEE (IF REQUIRED) MUST BE PAID WITHIN THREE MONTHS FROM THE MAILING DATE OF THIS NOTICE OR THIS APPLICATION SHALL BE REGARDED AS ABANDONED. THIS STATUTORY PERIOD CANNOT BE EXTENDED. SEE 35 U.S.C. 151. THE ISSUE FEE DUE INDICATED ABOVE REFLECTS A CREDIT FOR ANY PREVIOUSLY PAID ISSUE FEE APPLIED IN THIS APPLICATION. THE PTOL-85B (OR AN EQUIVALENT) MUST BE RETURNED WITHIN THIS PERIOD EVEN IF NO FEE IS DUE OR THE APPLICATION WILL BE REGARDED AS ABANDONED.

HOW TO REPLY TO THIS NOTICE:

I. Review the SMALL ENTITY status shown above.

If the SMALL ENTITY is shown as YES, verify your current SMALL ENTITY status:

A. If the status is the same, pay the TOTAL FEE(S) DUE shown above.

B. If the status is changed, pay the PUBLICATION FEE (if required) and twice the amount of the ISSUE FEE shown above and notify the United States Patent and Trademark Office of the change in status, or

If the SMALL ENTITY is shown as NO:

A. Pay TOTAL FEE(S) DUE shown above, or

B. If applicant claimed SMALL ENTITY status before, or is now claiming SMALL ENTITY status, check the box below and enclose the PUBLICATION FEE and 1/2 the ISSUE FEE shown above.

Applicant claims SMALL ENTITY status.
 See 37 CFR 1.27.

II. PART B - FEE(S) TRANSMITTAL should be completed and returned to the United States Patent and Trademark Office (USPTO) with your ISSUE FEE and PUBLICATION FEE (if required). Even if the fee(s) have already been paid, Part B - Fee(s) Transmittal should be completed and returned. If you are charging the fee(s) to your deposit account, section "4b" of Part B - Fee(s) Transmittal should be completed and an extra copy of the form should be submitted.

III. All communications regarding this application must give the application number. Please direct all communications prior to issuance to Box ISSUE FEE unless advised to the contrary.

IMPORTANT REMINDER: Utility patents issuing on applications filed on or after Dec. 12, 1980 may require payment of maintenance fees. It is patentee's responsibility to ensure timely payment of maintenance fees when due.

PART B - FEE(S) TRANSMITTAL

Complete and send this form, together with applicable fee(s), to: Mail Box ISSUE FEE

Commissioner for Patents Alexandria, Virginia 22313-1450

(703)746-4000 **Fax**

INSTRUCTIONS: This form should be used for transmitting the ISSUE FEE and PUBLICATION FEE (if required). Blocks 1 through 4 should be completed where appropriate. All further correspondence including the Patent, advance orders and notification of maintenance fees will be mailed to the current correspondence address as indicated unless corrected below or directed otherwise in Block 1, by (a) specifying a new correspondence address; and/or (b) indicating a separate "FEE ADDRESS" for received and the separate of the second of the s

maintenance fee notifications. Note: A certificate of mailing can only be used for domestic mailings of the Fee(s) Transmittal. This certificate cannot be used for any other accompanying papers. Each additional paper, such as an assignment or formal drawing, must have its own certificate of mailing or transmission. CURRENT CORRESPONDENCE ADDRESS (Note: Legibly mark-up with any corrections or use Block 1) 05/02/2003 SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938 Certificate of Mailing or Transmission I hereby certify that this Fee(s) Transmittal is being deposited with the United States Postal Service with sufficient postage for first class mail in an envelope addressed to the Box Issue Fee address above, or being facsimile Minneapolis, MN 55402 transmitted to the USPTO, on the date indicated below. (Depositor's name) FIRST NAMED INVENTOR ATTORNEY DOCKET NO. CONFIRMATION NO. APPLICATION NO. FILING DATE 1303.028US1 1837 09/945,554 08/30/2001 Leonard Forbes TITLE OF INVENTION: SRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATORS ISSUE FEE PUBLICATION FEE TOTAL FEE(S) DUE DATE DUE APPLN. TYPE SMALL ENTITY \$300 \$1600 08/04/2003 NO \$1300 nonprovisional CLASS-SUBCLASS **EXAMINER** ART UNIT 257-315000 DICKEY, THOMAS L 2826 1. Change of correspondence address or indication of "Fee Address" (37 CFR 1.363). 2. For printing on the patent front page, list (1) the names of up to 3 registered patent attorneys or agents OR, alternatively, (2) the name of a ☐ Change of correspondence address (or Change of Correspondence Address form PTO/SB/122) attached. single firm (having as a member a registered attorney or agent) and the names of up to 2 ☐ "Fee Address" indication (or "Fee Address" Indication form PTO/SB/47; Rev 03-02 or more recent) attached. Use of a Customer registered patent attorneys or agents. If no name is listed, no name will be printed. Number is required. 3. ASSIGNEE NAME AND RESIDENCE DATA TO BE PRINTED ON THE PATENT (print or type) PLEASE NOTE: Unless an assignee is identified below, no assignee data will appear on the patent. Inclusion of assignee data is only appropriate when an assignment has been previously submitted to the USPTO or is being submitted under separate cover. Completion of this form is NOT a substitute for filing an assignment. (B) RESIDENCE: (CITY and STATE OR COUNTRY) (A) NAME OF ASSIGNEE ☐ individual ☐ corporation or other private group entity ☐ government Please check the appropriate assignee category or categories (will not be printed on the patent) 4a. The following fee(s) are enclosed: 4b. Payment of Fee(s): A check in the amount of the fee(s) is enclosed. ☐ Issue Fee ☐ Payment by credit card. Form PTO-2038 is attached. ☐ Publication Fee ☐ The Commissioner is hereby authorized by charge the required fee(s), or credit any overpayment, to Deposit Account Number ______(enclose an extra copy of this form). ☐ Advance Order - # of Copies Deposit Account Number Commissioner for Patents is requested to apply the Issue Fee and Publication Fee (if any) or to re-apply any previously paid issue fee to the application identified above. (Authorized Signature) (Date) NOTE; The Issue Fee and Publication Fee (if required) will not be accepted from anyone other than the applicant; a registered attorney or agent; or the assignee or other party in interest as shown by the records of the United States Patent and Trademark Office.

This collection of information is required by 37 CFR 1.311. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 12 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, Alexandria, Virginia 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, Alexandria, Virginia 22313-1450. Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number.



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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/945,554	08/30/2001	Leonard Forbes	1303.028US1	1837
7590 05/02/2003 SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.		EXAMINER DICKEY, THOMAS L		
				P.O. Box 2938 Minneapolis, MN 5
Ψ1			2826	
			DATE MAILED: 05/02/2003	

Determination of Patent Term Adjustment under 35 U.S.C. 154 (b) (application filed on or after May 29, 2000)

The patent term adjustment to date is 0 days. If the issue fee is paid on the date that is three months after the mailing date of this notice and the patent issues on the Tuesday before the date that is 28 weeks (six and a half months) after the mailing date of this notice, the term adjustment will be 0 days.

If a continued prosecution application (CPA) was filed in the above-identified application, the filing date that determines patent term adjustment is the filing date of the most recent CPA.

Applicant will be able to obtain more detailed information by accessing the Patent Application Information Retrieval (PAIR) system. (http://pair.uspto.gov)

Any questions regarding the patent term extension or adjustment determination should be directed to the Office of Patent Legal Administration at (703)305-1383.



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09/945,554	08/30/2001	Leonard Forbes	1303.028US1	1837	
7590 05/02/2003		EXAMINER			
SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.			DICKEY, THOMAS L		
P.O. Box 2938 Minneapolis, MN 55402 UNITED STATES			ART UNIT	PAPER NUMBER	
			2826		
			DATE MAILED: 05/02/2003		

Notice of Fee Increase on January 1, 2003

If a reply to a "Notice of Allowance and Fee(s) Due" is filed in the Office on or after January 1, 2003, then the amount due will be higher than that set forth in the "Notice of Allowance and Fee(s) Due" since there will be an increase in fees effective on January 1, 2003. See Revision of Patent and Trademark Fees for Fiscal Year 2003; Final Rule, 67 Fed. Reg. 70847, 70849 (November 27, 2002).

The current fee schedule is accessible from: http://www.uspto.gov/main/howtofees.htm.

If the issue fee paid is the amount shown on the "Notice of Allowance and Fee(s) Due," but not the correct amount in view of the fee increase, a "Notice to Pay Balance of Issue Fee" will be mailed to applicant. In order to avoid processing delays associated with mailing of a "Notice to Pay Balance of Issue Fee," if the response to the Notice of Allowance and Fee(s) due form is to be filed on or after January 1, 2003 (or mailed with a certificate of mailing on or after January 1, 2003), the issue fee paid should be the fee that is required at the time the fee is paid. If the issue fee was previously paid, and the response to the "Notice of Allowance and Fee(s) Due" includes a request to apply a previously-paid issue fee to the issue fee now due, then the difference between the issue fee amount at the time the response is filed and the previously paid issue fee should be paid. See Manual of Patent Examining Procedure, Section 1308.01 (Eighth Edition, August 2001).

Questions relating to issue and publication fee payments should be directed to the Customer Service Center of the Office of Patent Publication at (703) 305-8283.